

# MC14001B Series

## B-Suffix Series CMOS Gates

MC14001B, MC14011B, MC14023B,  
MC14025B, MC14071B, MC14073B,  
MC14081B, MC14082B

The B Series logic gates are constructed with P and N channel enhancement mode devices in a single monolithic structure (Complementary MOS). Their primary use is where low power dissipation and/or high noise immunity is desired.

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range.
- Double Diode Protection on All Inputs Except: Triple Diode Protection on MC14011B and MC14081B
- Pin-for-Pin Replacements for Corresponding CD4000 Series B Suffix Devices

### MAXIMUM RATINGS (Voltages Referenced to $V_{SS}$ ) (Note 1)

Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage Range	-0.5 to +18.0	V
$V_{in}, V_{out}$	Input or Output Voltage Range (DC or Transient)	-0.5 to $V_{DD} + 0.5$	V
$I_{in}, I_{out}$	Input or Output Current (DC or Transient) per Pin	$\pm 10$	mA
$P_D$	Power Dissipation, per Package (Note 2)	500	mW
$T_A$	Ambient Temperature Range	-55 to +125	$^{\circ}C$
$T_{stg}$	Storage Temperature Range	-65 to +150	$^{\circ}C$
$T_L$	Lead Temperature (8-Second Soldering)	260	$^{\circ}C$

1. Maximum Ratings are those values beyond which damage to the device may occur.
2. Temperature Derating:  
Plastic "P and D/DW" Packages: - 7.0 mW/ $^{\circ}C$  From 65 $^{\circ}C$  To 125 $^{\circ}C$

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ .

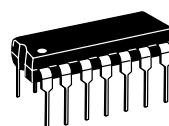
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



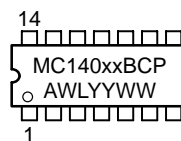
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### MARKING DIAGRAMS



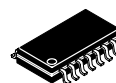
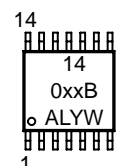
PDIP-14  
P SUFFIX  
CASE 646



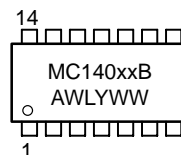
SOIC-14  
D SUFFIX  
CASE 751A



TSSOP-14  
DT SUFFIX  
CASE 948G



SOEIAJ-14  
F SUFFIX  
CASE 965



xx = Specific Device Code  
A = Assembly Location  
WL, L = Wafer Lot  
YY, Y = Year  
WW, W = Work Week

### DEVICE INFORMATION

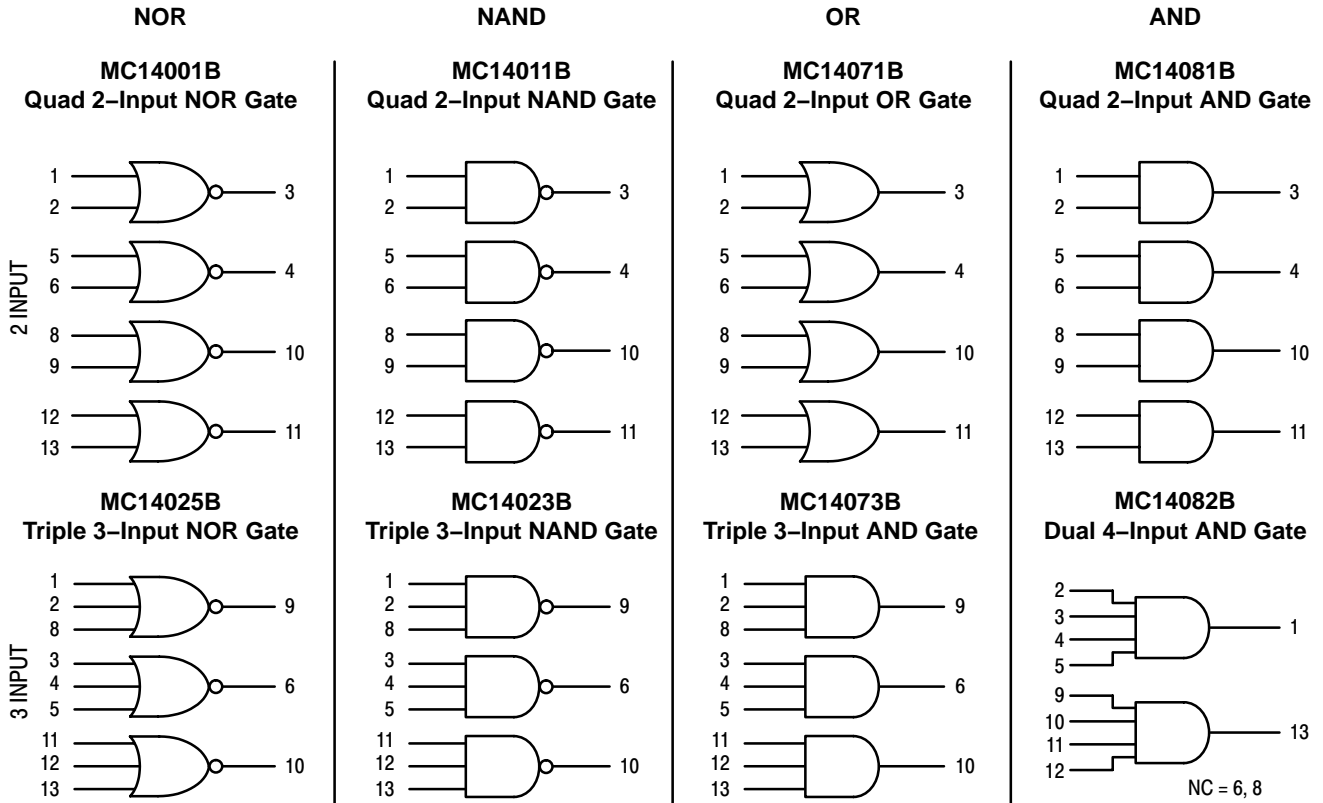
Device	Description
MC14001B	Quad 2-Input NOR Gate
MC14011B	Quad 2-Input NAND Gate
MC14023B	Triple 3-Input NAND Gate
MC14025B	Triple 3-Input NOR Gate
MC14071B	Quad 2-Input OR Gate
MC14073B	Triple 3-Input AND Gate
MC14081B	Quad 2-Input AND Gate
MC14082B	Dual 4-Input AND Gate

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 19 of this data sheet.

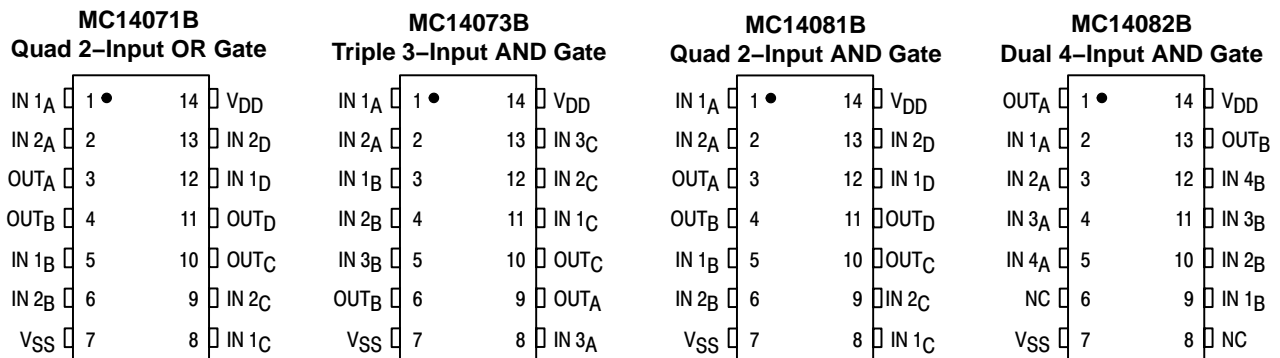
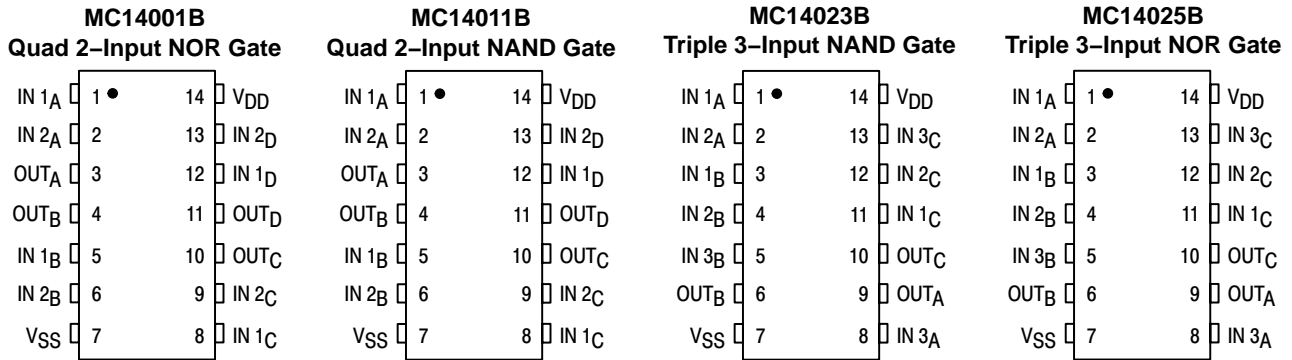
# MC14001B Series

## LOGIC DIAGRAMS



V<sub>DD</sub> = PIN 14  
V<sub>SS</sub> = PIN 7  
FOR ALL DEVICES

## PIN ASSIGNMENTS



NC = NO CONNECTION

# MC14001B Series

## ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

Characteristic	Symbol	V <sub>DD</sub> Vdc	- 55°C		25°C			125°C		Unit	
			Min	Max	Min	Typ (3)	Max	Min	Max		
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level V <sub>OL</sub>	5.0	—	0.05	—	0	0.05	—	0.05	Vdc	
		10	—	0.05	—	0	0.05	—	0.05		
		15	—	0.05	—	0	0.05	—	0.05		
	"1" Level V <sub>in</sub> = 0 or V <sub>DD</sub>	V <sub>OH</sub>	5.0	4.95	—	4.95	5.0	—	4.95		—
			10	9.95	—	9.95	10	—	9.95		—
			15	14.95	—	14.95	15	—	14.95		—
Input Voltage (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	"0" Level V <sub>IL</sub>	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc	
		10	—	3.0	—	4.50	3.0	—	3.0		
		15	—	4.0	—	6.75	4.0	—	4.0		
	"1" Level (V <sub>O</sub> = 0.5 or 4.5 Vdc) (V <sub>O</sub> = 1.0 or 9.0 Vdc) (V <sub>O</sub> = 1.5 or 13.5 Vdc)	V <sub>IH</sub>	5.0	3.5	—	3.5	2.75	—	3.5		—
			10	7.0	—	7.0	5.50	—	7.0		—
			15	11	—	11	8.25	—	11		—
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)	Source	I <sub>OH</sub>	5.0	-3.0	—	-2.4	-4.2	—	-1.7	—	mAdc
		5.0	-0.64	—	-0.51	-0.88	—	-0.36	—		
		10	-1.6	—	-1.3	-2.25	—	-0.9	—		
		15	-4.2	—	-3.4	-8.8	—	-2.4	—		
	Sink	I <sub>OL</sub>	5.0	0.64	—	0.51	0.88	—	0.36	—	
			10	1.6	—	1.3	2.25	—	0.9	—	
15	4.2	—	3.4	8.8	—	2.4	—	—			
Input Current	I <sub>in</sub>	15	—	± 0.1	—	± 0.00001	± 0.1	—	± 1.0	μAdc	
Input Capacitance (V <sub>in</sub> = 0)	C <sub>in</sub>	—	—	—	—	5.0	7.5	—	—	pF	
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0	—	0.25	—	0.0005	0.25	—	7.5	μAdc	
		10	—	0.5	—	0.0010	0.5	—	15		
		15	—	1.0	—	0.0015	1.0	—	30		
Total Supply Current (4) (5) (Dynamic plus Quiescent, Per Gate, C <sub>L</sub> = 50 pF)	I <sub>T</sub>	5.0	I <sub>T</sub> = (0.3 μA/kHz) f + I <sub>DD</sub> /N I <sub>T</sub> = (0.6 μA/kHz) f + I <sub>DD</sub> /N I <sub>T</sub> = (0.9 μA/kHz) f + I <sub>DD</sub> /N							μAdc	

3. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

4. The formulas given are for the typical characteristics only at 25°C.

5. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) Vfk$$

where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.001 x the number of exercised gates per package.

# MC14001B Series

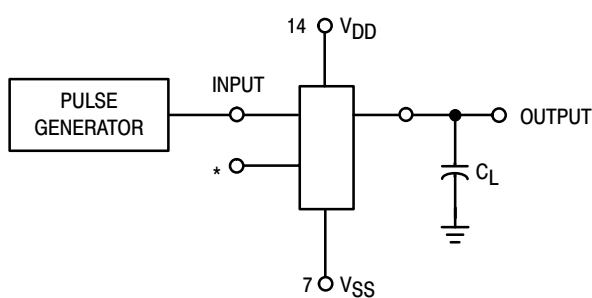
## B-SERIES GATE SWITCHING TIMES

### SWITCHING CHARACTERISTICS (6) ( $C_L = 50 \text{ pF}$ , $T_A = 25^\circ\text{C}$ )

Characteristic	Symbol	$V_{DD}$ Vdc	Min	Typ (7)	Max	Unit
Output Rise Time, All B-Series Gates $t_{TLH} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$ $t_{TLH} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{TLH} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$	$t_{TLH}$	5.0 10 15	— — —	100 50 40	200 100 80	ns
Output Fall Time, All B-Series Gates $t_{THL} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$ $t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$	$t_{THL}$	5.0 10 15	— — —	100 50 40	200 100 80	ns
Propagation Delay Time MC14001B, MC14011B only $t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 80 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 32 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 27 \text{ ns}$ All Other 2, 3, and 4 Input Gates $t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 115 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 47 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 37 \text{ ns}$ 8-Input Gates (MC14068B, MC14078B) $t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 155 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 62 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 47 \text{ ns}$	$t_{PLH}, t_{PHL}$	5.0 10 15  5.0 10 15  5.0 10 15	— — —  — — —  — — —	125 50 40  160 65 50  200 80 60	250 100 80  300 130 100  350 150 110	ns

6. The formulas given are for the typical characteristics only at  $25^\circ\text{C}$ .

7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



\*All unused inputs of AND, NAND gates must be connected to  $V_{DD}$ .  
 All unused inputs of OR, NOR gates must be connected to  $V_{SS}$ .

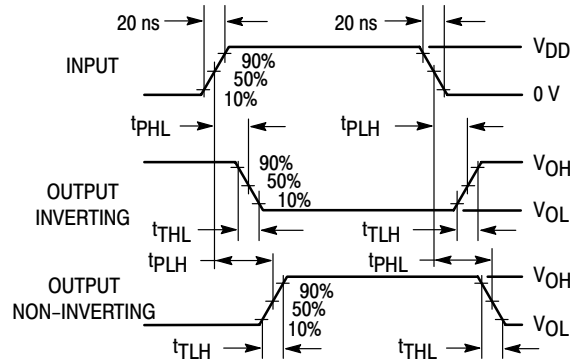
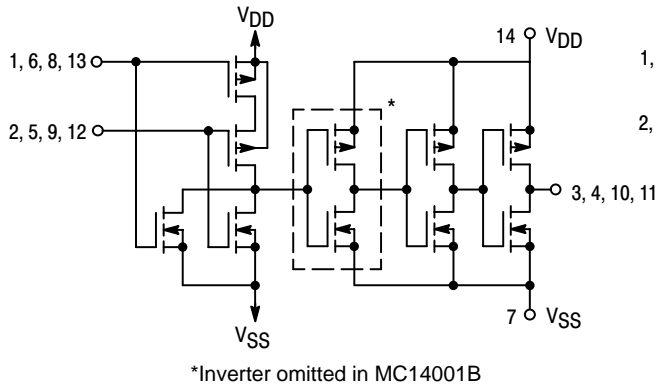


Figure 1. Switching Time Test Circuit and Waveforms

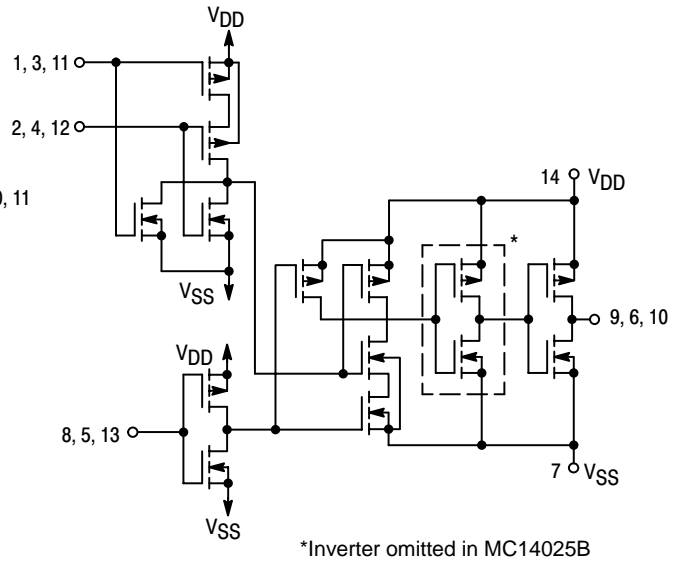
# MC14001B Series

## CIRCUIT SCHEMATIC NOR, OR GATES

**MC14001B, MC14071B**  
One of Four Gates Shown

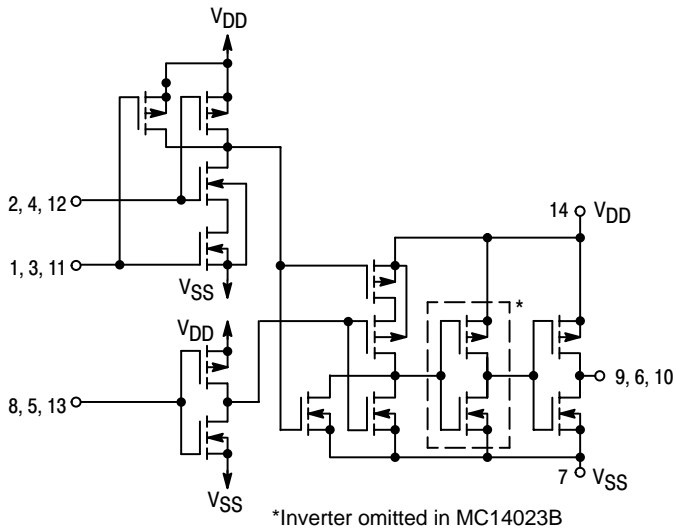


**MC14025B**  
One of Three Gates Shown

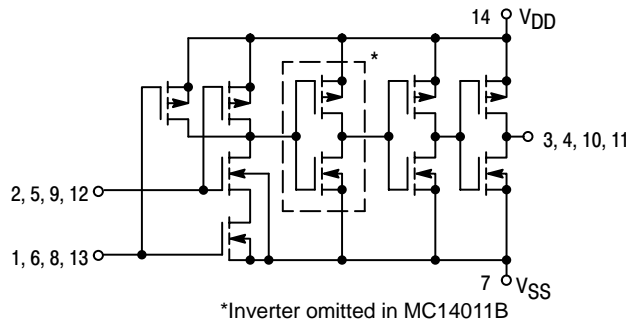


## CIRCUIT SCHEMATIC NAND, AND GATES

**MC14023B, MC14073B**  
One of Three Gates Shown



**MC14011B, MC14081B**  
One of Four Gates Shown



# MC14001B Series

## TYPICAL B-SERIES GATE CHARACTERISTICS

### N-CHANNEL DRAIN CURRENT (SINK)

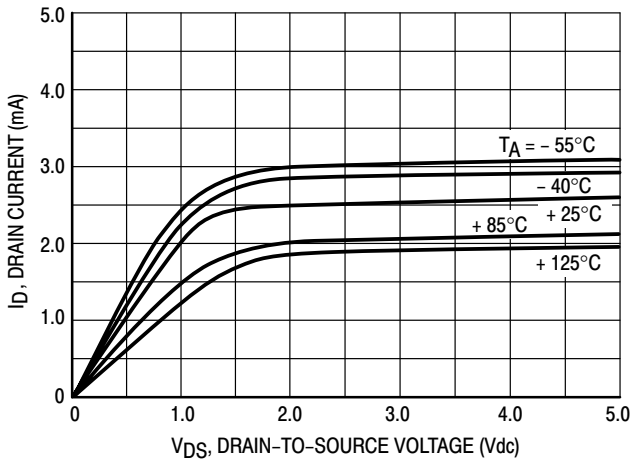


Figure 2.  $V_{GS} = 5.0 \text{ Vdc}$

### P-CHANNEL DRAIN CURRENT (SOURCE)

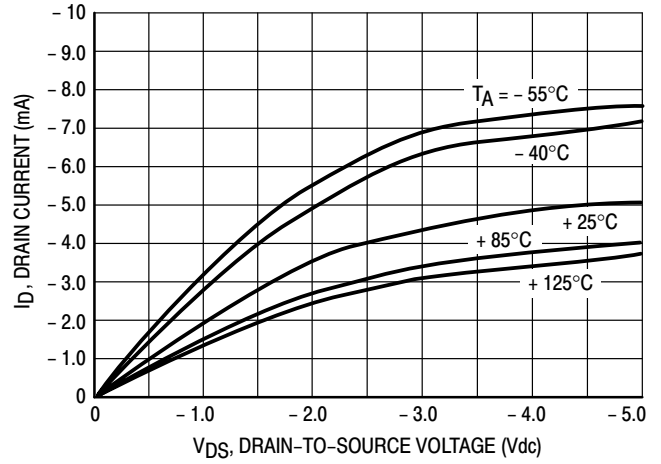


Figure 3.  $V_{GS} = -5.0 \text{ Vdc}$

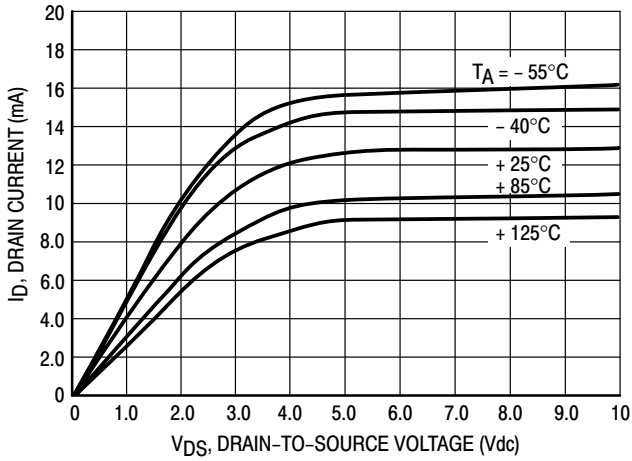


Figure 4.  $V_{GS} = 10 \text{ Vdc}$

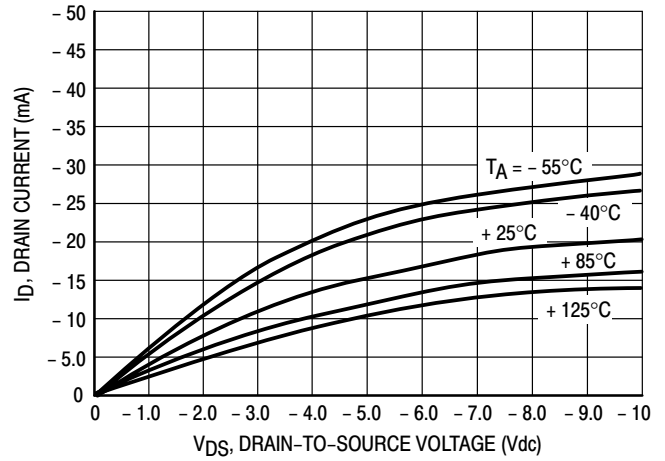


Figure 5.  $V_{GS} = -10 \text{ Vdc}$

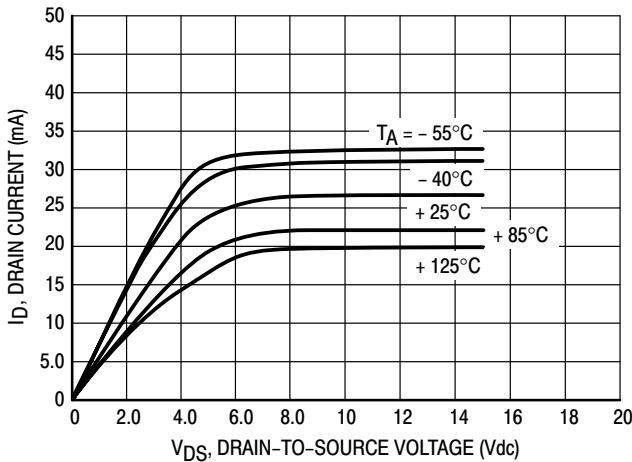


Figure 6.  $V_{GS} = 15 \text{ Vdc}$

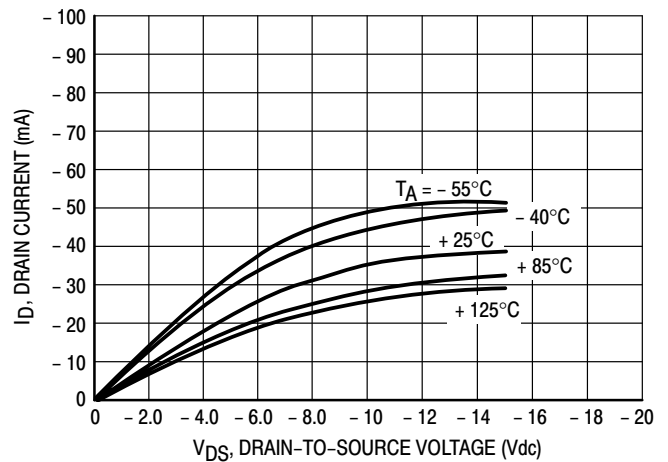


Figure 7.  $V_{GS} = -15 \text{ Vdc}$

These typical curves are not guarantees, but are design aids.  
 Caution: The maximum rating for output current is 10 mA per pin.

# MC14001B Series

## TYPICAL B-SERIES GATE CHARACTERISTICS (cont'd)

### VOLTAGE TRANSFER CHARACTERISTICS

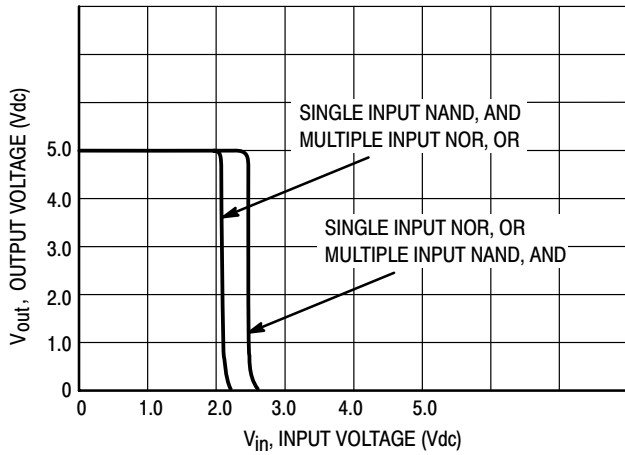


Figure 8.  $V_{DD} = 5.0$  Vdc

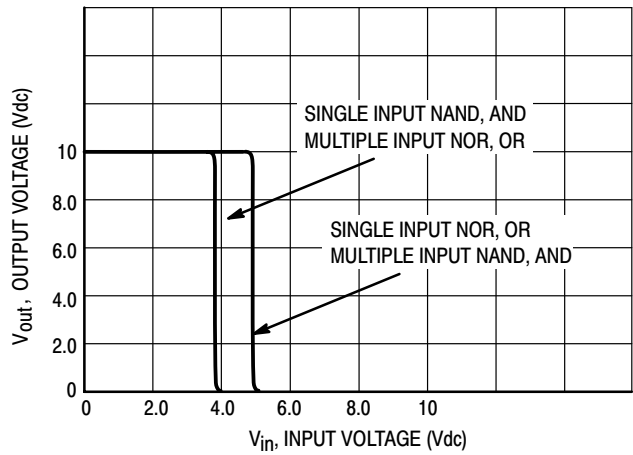


Figure 9.  $V_{DD} = 10$  Vdc

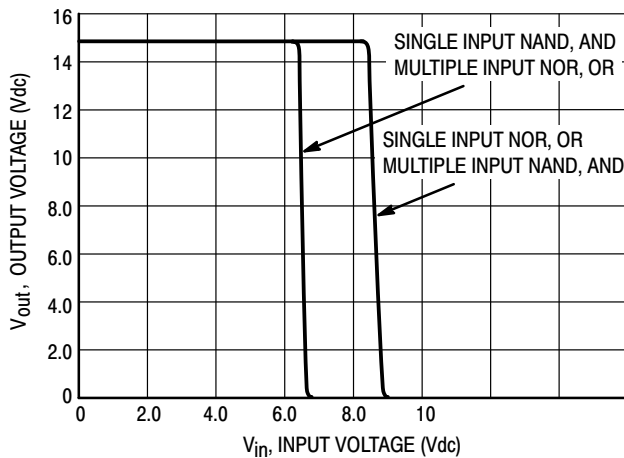


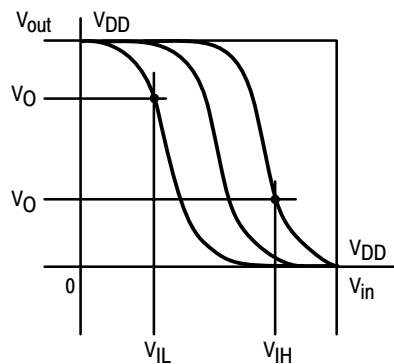
Figure 10.  $V_{DD} = 15$  Vdc

### DC NOISE MARGIN

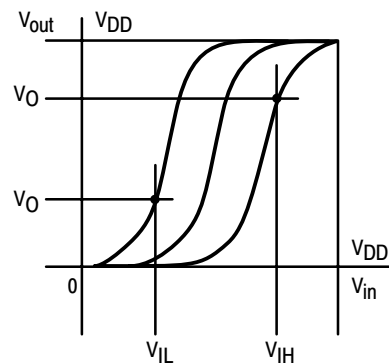
The DC noise margin is defined as the input voltage range from an ideal “1” or “0” input level which does not produce output state change(s). The typical and guaranteed limit values of the input values  $V_{IL}$  and  $V_{IH}$  for the output(s) to be at a fixed voltage  $V_O$  are given in the Electrical Characteristics table.  $V_{IL}$  and  $V_{IH}$  are presented graphically in Figure 11.

Guaranteed minimum noise margins for both the “1” and “0” levels =

- 1.0 V with a 5.0 V supply
- 2.0 V with a 10.0 V supply
- 2.5 V with a 15.0 V supply



(a) Inverting Function



(b) Non-Inverting Function

$V_{SS} = 0$  VOLTS DC

Figure 11. DC Noise Immunity

## MC14001B Series

### ORDERING & SHIPPING INFORMATION:

Device	Package	Shipping
MC14001BCP	PDIP-14	2000 Units per Box
MC14001BD	SOIC-14	2750 Units per Box
MC14001BDR2	SOIC-14	2500 Units / Tape & Reel
MC14001BDT	TSSOP-14	96 Units per Rail
MC14001BDTR2	TSSOP-14	2500 Units / Tape & Reel
MC14011BCP	PDIP-14	2000 Units per Box
MC14011BD	SOIC-14	2750 Units per Box
MC14011BDR2	SOIC-14	2500 Units / Tape & Reel
MC14011BDT	TSSOP-14	96 Units per Rail
MC14011BDTEL	TSSOP-14	2000 Units / Tape & Reel
MC14011BDTR2	TSSOP-14	2500 Units / Tape & Reel
MC14023BCP	PDIP-14	2000 Units per Box
MC14023BD	SOIC-14	2750 Units per Box
MC14023BDR2	SOIC-14	2500 Units / Tape & Reel
MC14025BCP	PDIP-14	2000 Units per Box
MC14025BD	SOIC-14	2750 Units per Box
MC14025BDR2	SOIC-14	2500 Units / Tape & Reel

### ORDERING & SHIPPING INFORMATION:

Device	Package	Shipping
MC14071BCP	PDIP-14	2000 Units per Box
MC14071BD	SOIC-14	55 Units per Rail
MC14071BDR2	SOIC-14	2500 Units / Tape & Reel
MC14071BDT	TSSOP-14	96 Units per Rail
MC14071BDTR2	TSSOP-14	2500 Units / Tape & Reel
MC14073BCP	PDIP-14	2000 Units per Box
MC14073BD	SOIC-14	55 Units per Rail
MC14073BDR2	SOIC-14	2500 Units / Tape & Reel
MC14081BCP	PDIP-14	2000 Units per Box
MC14081BD	SOIC-14	55 Units per Rail
MC14081BDR2	SOIC-14	2500 Units / Tape & Reel
MC14081BDT	TSSOP-14	96 Units per Rail
MC14081BDTR2	TSSOP-14	2500 Units / Tape & Reel
MC14082BCP	PDIP-14	2000 Units per Box
MC14082BD	SOIC-14	55 Units per Rail
MC14082BDR2	SOIC-14	2500 Units / Tape & Reel

For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.